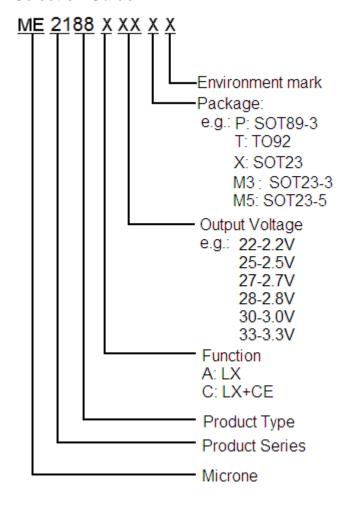


## High Efficiency, synchronous PFM step-up DC-DC converter

### **General Description**

ME2188 Series is a PFM Step-up DC/DC converter IC with low supply current by CMOS process. High frequency noise that occurs during switching is reduced by using advanced circuit designed, output voltage is programmable in 0.1V steps between 1.8V~5.0V and maximum frequency is 350KHz(TYP.). A low ripple, high efficiency step-up DC/DC converter can be constructed of ME2188Xxx with only two external components. ME2188Xxx is suitable for use with battery-powered instruments with low noise and low supply current.

#### **Selection Guide**



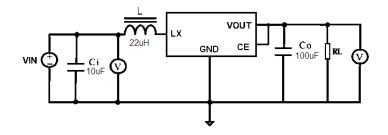
#### **Features**

- High efficiency: 95%
- Maximum frequency: 350KHz
- Low Quiescent Current: 13μA
- Input Voltage: 0.9V~5.0V
- Output Voltage Range:1.8V to 5.0V
- High Accuracy: ± 2%
- Low ripple and Low noise
- Package: SOT23-3, SOT23-5, SOT23, SOT89-3, TO-92

### **Typical Application**

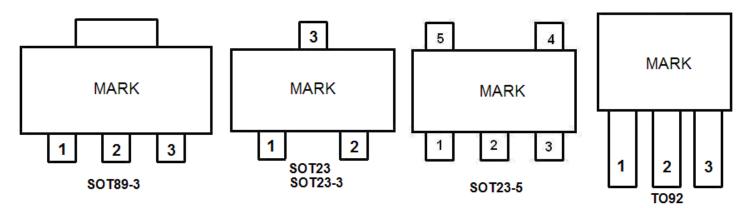
- Power source for battery-powered equipment
- Power source for Wireless mouse,toys,
   Cameras, VCRs, PDAs, MP3, and Led lighting etc

## **Typical Application Circuit**





# **Pin Configuration**



**Pin Assignment** 

TVDE	POSTFIX	PACKAGE	SWITCHING	of function	FEATURES
TYPE			TRANSISTOR	CE FUNCTION	
	Х	SOT23			Lx
ME2400Avo	M3	SOT23-3	Build in Transistor	No	
ME2188Axx	Р	SOT89-3			
	Т	TO92			
ME2188Cxx	M5	SOT23-5	Build in Transistor	Yes	LX+CE

## ME2188AXX

Pin Number				Pin Name	Description
SOT89-3	SOT23-3	SOT23	TO-92		
1	1	1	1	GND	Ground
2	3	3	2	VOUT	Voltage output
3	2	2	3	LX	Switch pin

#### ME2188CXX

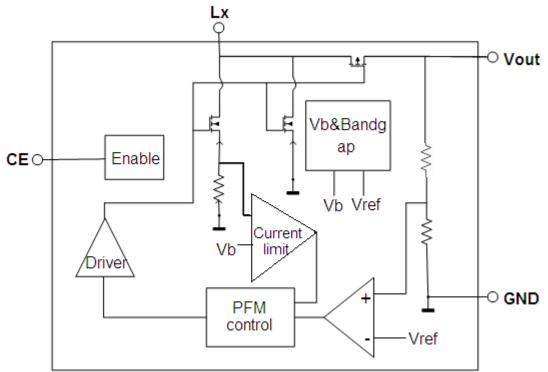
PIN Number	Pin Name	Description	
SOT23-5	Pili Name	Description	
1	CE	Chip enable	
2	VOUT	Output voltage monitor, IC internal power supply	
3	NC	NC	
4	GND	Ground	
5	LX	Switch	



# **Absolute Maximum Ratings**

Parameter	Symbol	Ratings	Units	
Supply Voltage	$V_{MAX}$	8	V	
LX pin current		ILXmax	1000	mA
	SOT23	P <sub>D</sub>	300	mW
Continuous Total Power Dissipation	SOT89	P <sub>D</sub>	500	mW
	TO92	P <sub>D</sub>	500	mW
Operating Temperature Rai	T <sub>OPR</sub>	-20~+85	$^{\circ}$	
Storage Temperature Range		T <sub>STG</sub>	-40~125	$^{\circ}$
ESD		$V_{ESD}$	2000	V

# Block Diagram





#### **Electrical Characteristics**

 $T_A=25^{\circ}C$ ,  $V_{in}=V_{OUT}\times0.6V$ ,  $L=22\mu H$ ,  $C_{IN}=10\mu F$ ,  $C_{OUT}=100\mu F$ , unless otherwise noted.

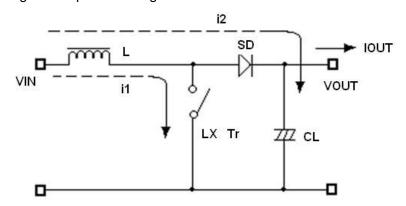
#### ME2188Axx/Cxx

Symbol	Parameter	Test Conditions	MIN	TYP	MAX	UNIT
V <sub>OUT</sub>	Output Voltage		$V_{OUT} \times 0.98$	V <sub>OUT</sub>	V <sub>OUT</sub> ×1.02	V
V <sub>IN</sub>	Supply Voltage		0.9	-	5	V
V <sub>START</sub>	Start voltage	Iload=1mA, Vin: 0→2V	-	0.85	1.1	V
Vhold	Hold voltage	Iload=1mA, Vin: 2→0V	0.5	-	-	V
Fosc	oscillation frequency		-	350	-	KHz
η	Efficiency		-	90	95	%
llimit	Current limit		800	1000	1200	mA
I <sub>IN</sub>	Quiescent Current		-	13	15	μA

Note: 1. Inductor:  $22\mu H (r<0.5\Omega)$ 2. Capacitor: Tantalum type

### **Operation Description**

ME2188 step-up DC/DC converter charges energy in the inductor when Lx Transistor is on, and discharges the energy with the addition of the energy from input power source thereto, so that a higher output voltage than the input voltage is obtained. Following is the operation diagram.



Switching DC/DC Step up Converter operating process

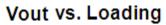
### PCB Layout:

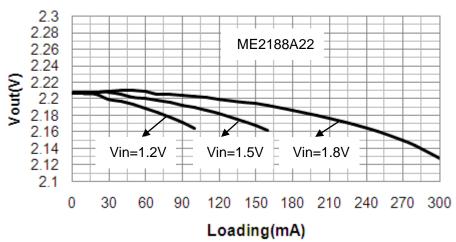
- ♦ Set external components as close as possible to the IC and minimize the connection between the components and the IC. In particular, when an external component is connected to VOUT Pin, make minimum connection with the capacitor.
- ♦ Make Vss pin sufficient grounding, otherwise, the zero level within IC will varied with the switching current. This may result in unstable operation of IC.

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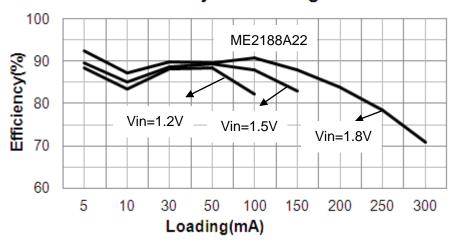


# **Type Characteristics**

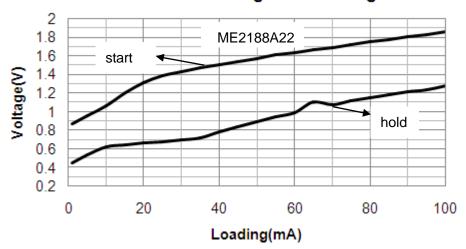




# Efficiency vs. Loading

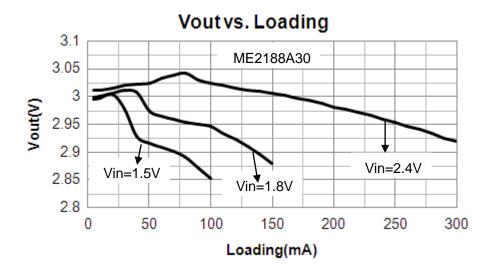


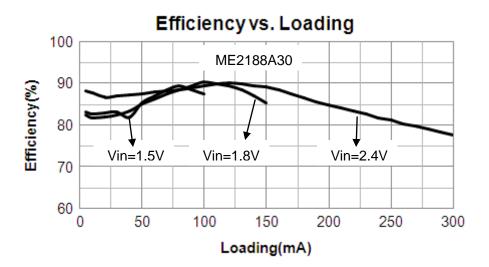
# Start and Hold Voltage vs. Loading

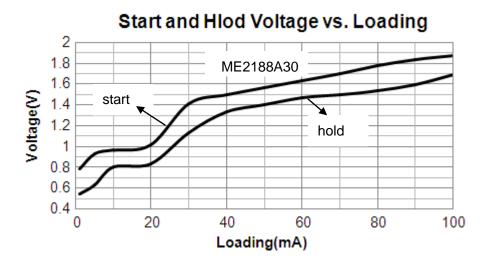


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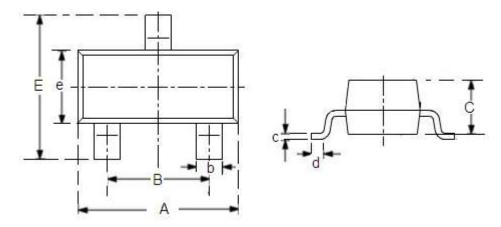






# **Packaging Information**

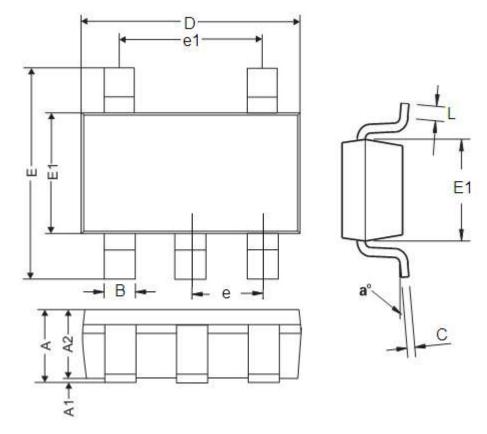
## ● SOT23-3



DIM	Millim	eters	Inches	
DIM	Min	Max	Min	Max
А	2.7	3.1	0.1063	0.122
В	1.7	2.1	0.0669	0.0827
b	0.35	0.5	0.0138	0.0197
С	1.0	1.2	0.0394	0.0472
С	0.1	0.25	0.0039	0.0098
d	0.2	-	0.0079	-
E	2.6	3.0	0.1023	0.1181
е	1.5	1.8	0.059	0.0708



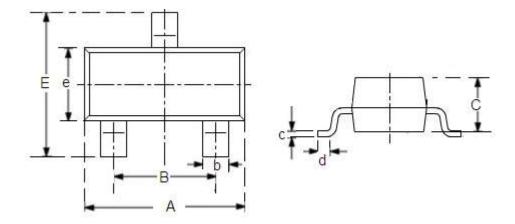
# ● SOT23-5



DIM	Millim	neters	Inches		
DIM	Min	Max	Min	Max	
А	0.9	1.45	0.0354	0.0570	
A1	0	0.15	0	0.0059	
A2	0.9	1.3	0.0354	0.0511	
В	0.2	0.5	0.0078	0.0196	
С	0.09	0.26	0.0035	0.0102	
D	2.7	3.10	0.1062	0.1220	
Е	2.2	3.2	0.0866	0.1181	
E1	1.30	1.80	0.0511	0.0708	
е	0.95	0.95REF 0.0374REF		374REF	
e1	1.90REF		0.0748REF		
L	0.10	0.60	0.0039	0.0236	
a <sup>0</sup>	00	30 <sup>0</sup>	00	30°	



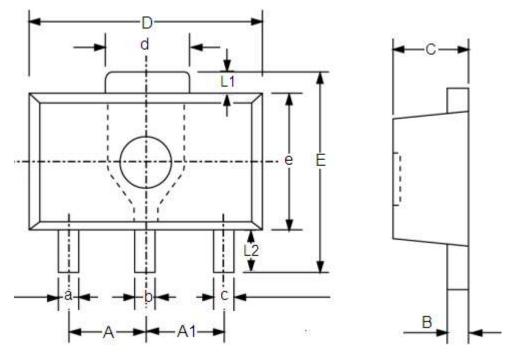
# • SOT23



DIM	Millim	eters	Inches	
	Min	Max	Min	Max
А	2.7	3.1	0.1063	0.122
В	1.7	2.1	0.0669	0.0827
b	0.35	0.5	0.0138	0.0197
С	1.0	1.2	0.0394	0.0472
С	0.1	0.25	0.0039	0.0098
d	0.2	-	0.0079	-
E	2.1	2.64	0.0827	0.1039
е	1.2	1.4	0.0472	0.0551



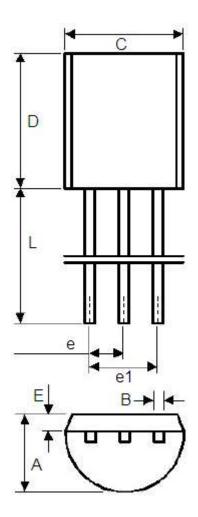
## ● SOT89-3



DIM	Millimeters		Inches	
DIM	Min	Max	Min	Max
А	1.4	1.6	0.0551	0.0630
A1	1.4	1.6	0.0551	0.0630
а	0.36	0.48	0.0142	0.0189
b	0.41	0.53	0.0161	0.0209
С	0.36	0.48	0.0142	0.0189
d	1.4	1.75	0.0551	0.0689
В	0.38	0.43	0.015	0.0169
С	1.4	1.6	0.0551	0.0630
D	4.4	4.6	0.1732	0.181
Е	-	4.25	-	0.1673
е	2.4	2.6	0.0945	0.1023
L1	0.4	-	0.0157	-
L2	0.8	-	0.0315	-



# ● TO-92



DIM	Millin	neters	Inches		
DIM	Min	Max	Min	Max	
А	3.4	3.8	0.13386	0.1496	
В	0.3	0.5	0.0118	0.0197	
С	4.4	4.8	0.1732	0.189	
D	4.4	4.8	0.1732	0.189	
Е	0.9	1.5	0.0354	0.059	
е	1.17	1.37	0.046	0.0539	
e1	2.39	2.69	0.094	0.1059	
L	12	16	0.4724	0.6299	



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